FAIRCHILD SEMICONDUCTOR

FPDB20PH60

Smart Power Module for Front-End Rectifier

General Description

FPDB20PH60 is an advanced smart power module of PFC(Power Factor Correction) that Fairchild has newly developed and designed mainly targeting mid-power application especially for an air conditioners. It combines optimized circuit protection and drive IC matched to high frequency switching IGBTs. System reliability is futher enhanced by the integrated under-voltage lock-out and over-current protection function.

Features

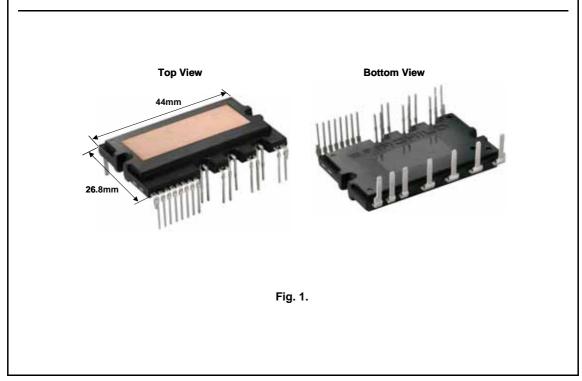
- Low thermal resistance due to Al₂O₃-DBC substrate
- 600V-20A 2-phase IGBT PWM semi-converter including a drive IC for gate driving and protection

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- Typical switching frequency of 20kHz
- Isolation rating of 2500Vrms/min.

Applications

• AC 180V ~ 264V single-phase front-end rectifier



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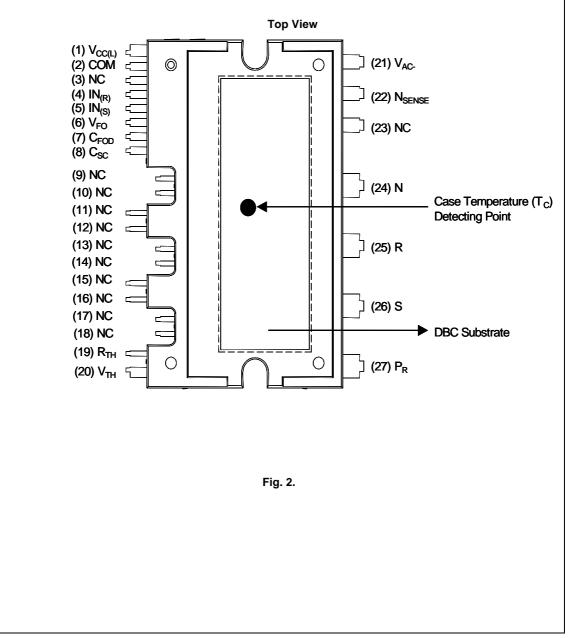
Integrated Power Functions

• PFC converter for single-phase AC/DC power conversion (Please refer to Fig. 3)

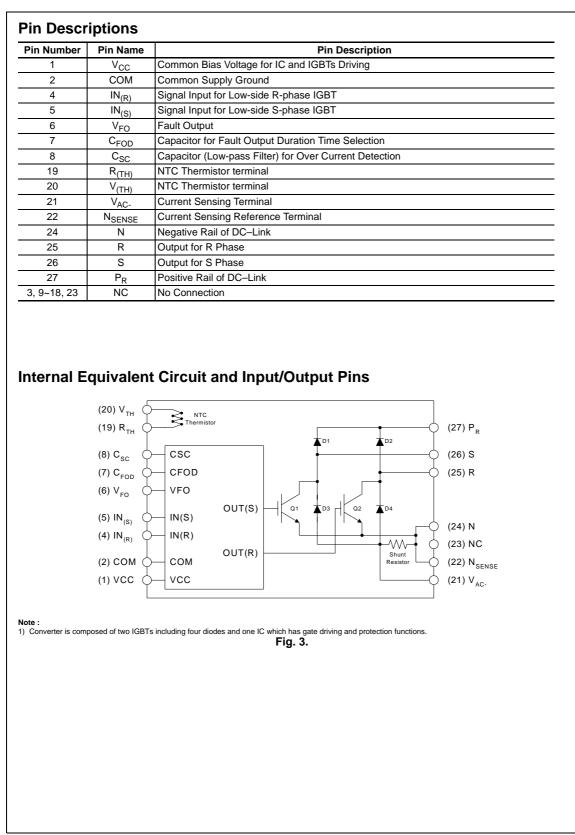
Integrated Drive, Protection and System Control Functions

- For IGBTs: Gate drive circuit, Overcurrent circuit protection (OC), Control supply circuit under-voltage (UV) protection
- Fault signaling: Corresponding to a UV fault
- Input interface: 5V CMOS/LSTTL compatible, Schmitt trigger input

Pin Configuration



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Absolute Maximum Ratings (T_J = 25°C, Unless Otherwise Specified) **Converter Part**

ltem	Symbol	Condition	Rating	Unit	
Supply Voltage	Vi	V _i Applied between R-S		V _{RMS}	
Supply Voltage (Surge)	V _{i(Surge)}	Applied between R-S	500	V	
Output Voltage	V _{PN}	Applied between P- N	450	V	
Output Voltage (Surge)	V _{PN(Surge)}	Applied between P- N	500	V	
Collector-emitter Voltage	V _{CES}		600	V	
Input Current (100% Load)	li	T _C < 95°C, V _i =220V, V _{PN} = 390V, V _{PWM} =20kHz	12	A	
Input Current (125% Load)	I _{i(125%)}	T _C < 95°C, V _i =220V, V _{PN} = 390V, V _{PWM} =20kHz, 1min Non-repetitive	15	A	
Collector Dissipation	P _C	T _C = 25°C per One IGBT	62.5	W	
Power Rating of Shunt Resistor	P _{RSH}	T _C < 125°C	1.5	W	
Operating Junction Temperature	ТJ	(Note 1)	-20 ~ 125	°C	

Note 1. The maximum junction temperature rating of the power chips integrated within the SPM is 150 °C(@T_C \leq 100°C). However, to insure safe operation of the SPM, the average junction temperature should be limited to T_{J(ave)} \leq 125°C (@T_C \leq 100°C).

Control Part

ltem	Symbol	Condition	Rating	Unit
Control Supply Voltage	V _{CC}	Applied between V _{CC} - COM	20	V
Input Signal Voltage	V _{IN}	Applied between IN - COM	-0.3~5.5	V
Fault Output Supply Voltage	V _{FO}	Applied between V _{FO} - COM	-0.3~V _{CC} +0.3	V
Fault Output Current	I _{FO}	Sink Current at V _{FO} Pin	5	mA
Current Sensing Input Voltage	V _{SC}	Applied between C _{SC} - COM	-0.3~V _{CC} +0.3	V

Total System

Item	Symbol	Condition	Rating	Unit
Module Case Operation Temperature	Т _С		-20 ~ 100	°C
Storage Temperature	T _{STG}		-40 ~ 125	°C
Isolation Voltage	V _{ISO}	60Hz, Sinusoidal, AC 1 minute, Connection Pins to DBC	2500	V _{rms}

Thermal Resistance

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
Junction to Case Thermal	R _{θ(j-c)Q}	IGBT	-	-	1.6	°C/W
Resistance	R _{θ(j-c)HD}	High-side diode	-	-	2.4	°C/W
(Referenced to chip center)	$R_{\theta(j-c)LD}$	Low-side diode	-	-	1.9	°C/W

Note :

2. For the measurement point of case temperature(T_C), please refer to Fig. 2.

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Electrical Characteristics (T_J = 25°C, Unless Otherwise Specified) **Converter Part**

Item	Symbol	Condition	Min.	Тур.	Max.	Unit
IGBT saturation voltage	V _{CE(sat)}	V _{CC} =15V, V _{IN} = 5V; I _C =20A	-	2.4	3.0	V
High-side diode voltage	V _{FH}	I _F = 20A	-	1.9	2.7	V
Low-side diode voltage	V _{FL}	I _F = 20A	-	1.1	1.5	V
Switching Times	t _{ON}	V _{PN} = 400V, V _{CC} = 15V, I _C =20A	-	690	-	ns
-	t _{C(ON)}	$V_{IN} = 0V \leftrightarrow 5V$, Inductive Load	-	510	-	ns
	t _{OFF}	(Note 3)	-	450	-	ns
-	t _{C(OFF)}		-	120	-	ns
-	t _{rr}		-	50	-	ns
	I _{rr}		-	2	-	Α
Current sensing resistor	R _{SENSE}		3.6	4.0	4.4	mΩ
Collector - emitter Leakage Current	I _{CES}	$V_{CE} = V_{CES}$	-	-	250	μΑ

Note
t_{ON} and t_{OFF} include the propagation delay time of the internal drive IC. t_{C(ON)} and t_{C(OFF)} are the switching time of IGBT itself under the given gate driving condition internally. For the detailed information, please see Fig. 4

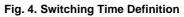
Control Part

Item	Symbol	C	ondition	Min.	Тур.	Max.	Unit
Quiescent V _{CC} Supply Current	IQCCL	V _{CC} = 15V, IN = 0V	V _{CC} - COM	-	-	26	mA
Fault Output Voltage	V _{FOH}	V _{SC} = 0V, V _{FO} Circui	t: 4.7kΩ to 5V Pull-up	4.5	-	-	V
	V _{FOL}	V _{SC} = 1V, V _{FO} Circui	$V_{SC} = 1V, V_{FO}$ Circuit: 4.7k Ω to 5V Pull-up		-	0.8	V
Over Current Trip Level	V _{SC(ref)}	V _{CC} = 15V		0.45	0.5	0.55	V
Supply Circuit Under-	UV _{CCD}	Detection Level		10.7	11.9	13.0	V
Voltage Protection	UV _{CCR}	Reset Level	eset Level		12.4	13.2	V
Fault-out Pulse Width	t _{FOD}	C _{FOD} = 33nF (Note 4)		1.4	1.8	2.0	ms
ON Threshold Voltage	V _{IN(ON)}	Applied between IN -	COM	3.0	-	-	V
OFF Threshold Voltage	V _{IN(OFF)}			-	-	0.8	V
Resistance of Thermistor	R _{TH}	@ T _C = 25°C (Note Fig. 9)		-	50	-	kΩ
		@ T _C = 80°C (Note Fig. 9)		-	5.76	-	kΩ

Note 4. The fault-out pulse width t_{FOD} depends on the capacitance value of C_{FOD} according to the following approximate equation : $C_{FOD} = 18.3 \times 10^{-6} \times t_{FOD}[F]$

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Mechanical Characteristics and Ratings

ltem		Condition			Limits		
nem		condition	Min.	Тур.	Max.	Units	
Mounting Torque	Mounting Screw: - M3	Recommended 0.62N•m	0.51	0.62	0.72	N∙m	
Device Flatness	Note Fig. 5	Note Fig. 5		-	+120	μm	
Weight			-	15.00	-	g	

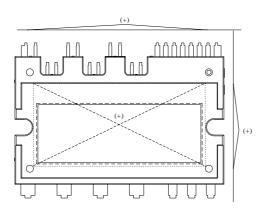
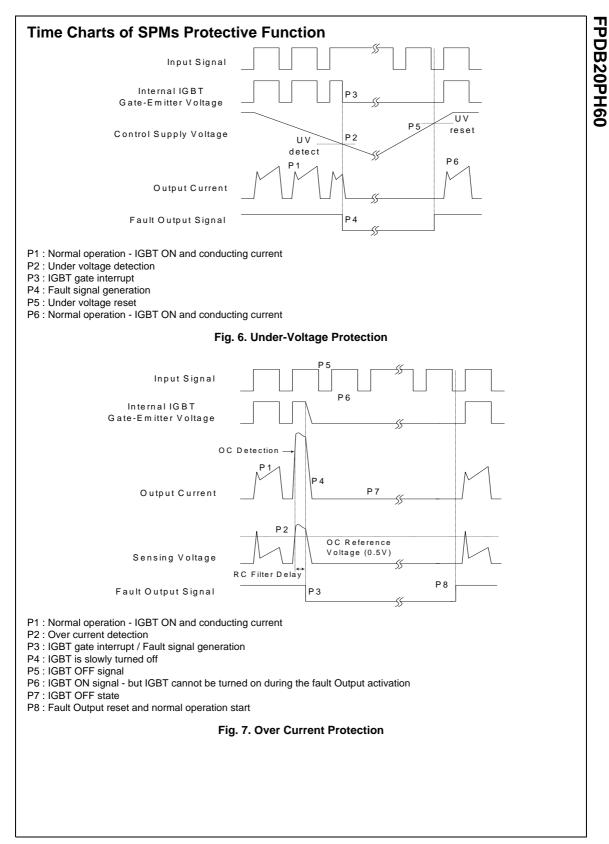
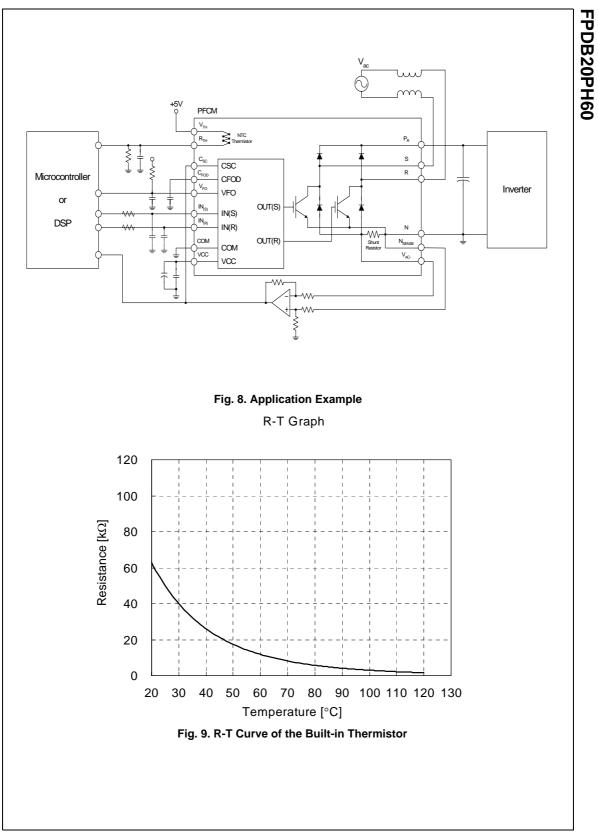


Fig. 5. Flatness Measurement Position

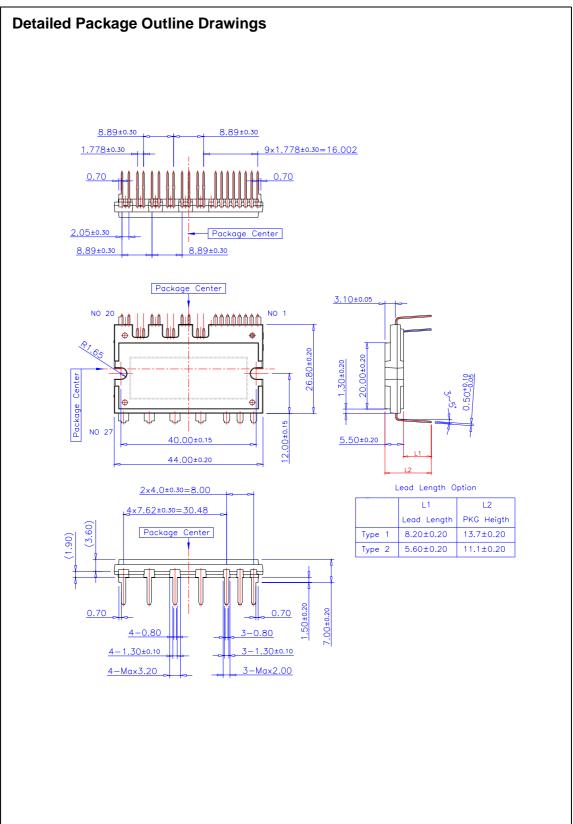
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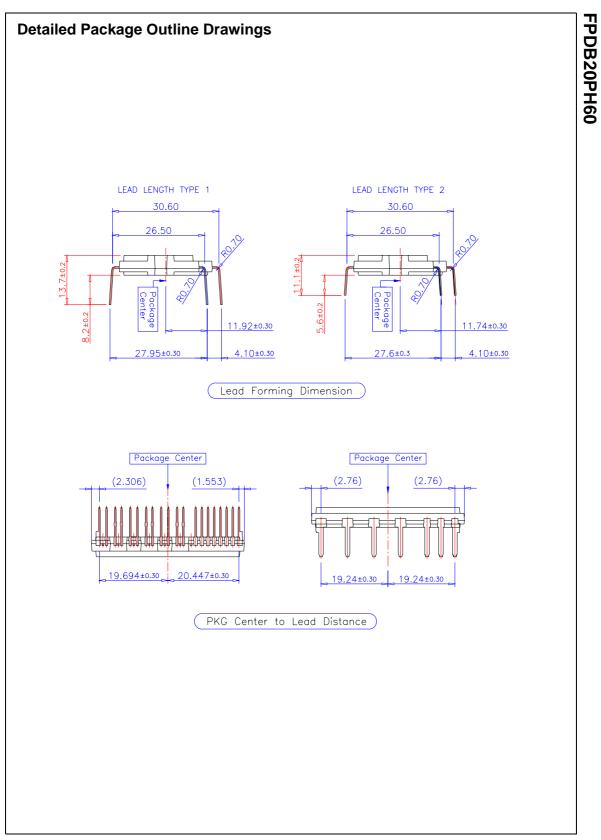


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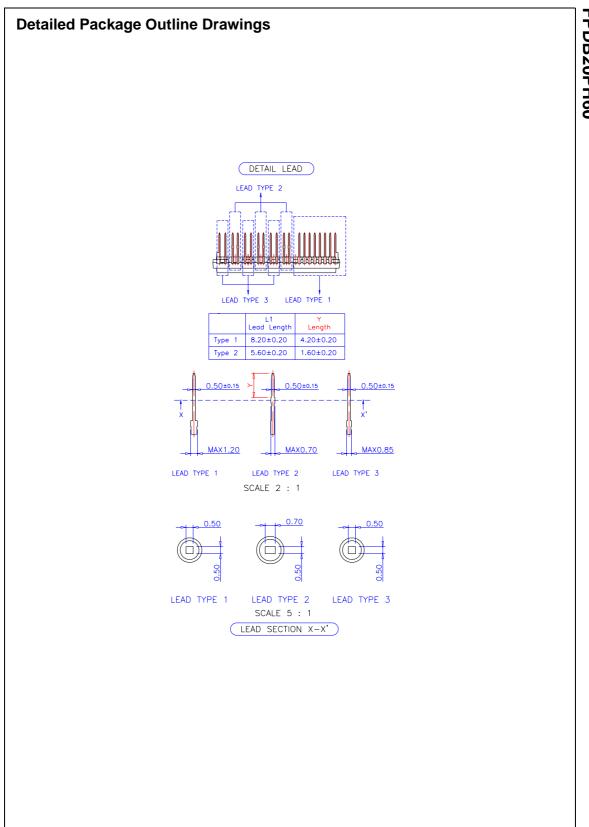


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		Rev. 118